TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSⅢ)

SSM6J21TU

High Current Switching Applications

- Suitable for high-density mounting due to compact package
- Low on resistance: R_{on} = 88 mΩ (max) (@V_{GS} = -2.5 V)

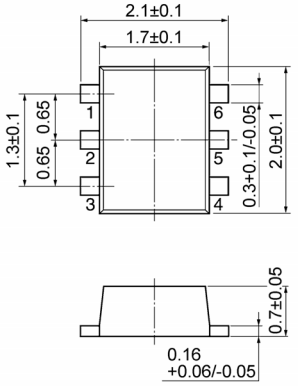
Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V_{DS}	-12	V
Gate-Source voltage		V_{GSS}	±12	V
Drain current	DC	I_D	-3	A
	Pulse	I_{DP}	-6	
Drain power dissipation		P_D (Note 1)	500	mW
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	−55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board.
(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 645 mm^2)

Unit: mm



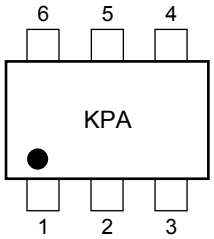
1,2,5,6 : Drain
3 : Gate
4 : Source

UF6

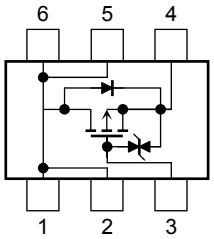
JEDEC	-
JEITA	-
TOSHIBA	2-2T1D

Weight: 7 mg (typ.)

Marking



Equivalent Circuit



Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic discharge. Operators should wear anti-static clothing and use containers and other objects that are made of anti-static materials.

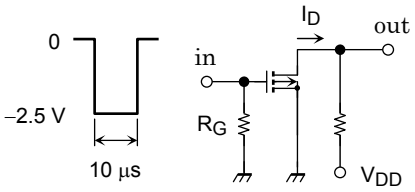
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	V_{GS} = ±10 V, V_{DS} = 0	–	–	±1	μA
Drain-Source breakdown voltage		$V_{(BR)\ DSS}$	I_D = -1 mA, V_{GS} = 0	-12	–	–	V
		$V_{(BR)\ DSX}$	I_D = -1 mA, V_{GS} = +8 V	-4	–	–	
Drain cut-off current		I_{DSS}	V_{DS} = -12 V, V_{GS} = 0	–	–	-1	μA
Gate threshold voltage		V_{th}	V_{DS} = -3 V, I_D = -0.1 mA	-0.5	–	-1.1	V
Forward transfer admittance		$\|Y_{fs}\|$	V_{DS} = -3 V, I_D = -1.5 A (Note2)	4.3	–	–	S
Drain-Source ON resistance		$R_{DS\ (ON)}$	I_D = -1.5 A, V_{GS} = -4 V (Note2)	–	35	50	mΩ
			I_D = -1.5 A, V_{GS} = -2.5 V (Note2)	–	50	88	
Input capacitance		C_{iss}	V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz	–	1300	–	pF
Reverse transfer capacitance		C_{rss}	V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz	–	330	–	pF
Output capacitance		C_{oss}	V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz	–	400	–	pF
Switching time	Turn-on time	t_{on}	–	–	68	–	ns
	Turn-off time	t_{off}		–	76	–	

Note2: Pulse test

Switching Time Test Circuit

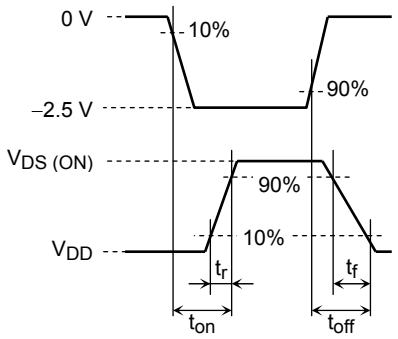
(a) Test Circuit



V_{DD} = -10 V
R_G = 4.7 Ω
D.U. ≦ 1%
V_{IN}: t_r, t_f < 5 ns
Common Source
Ta = 25°C

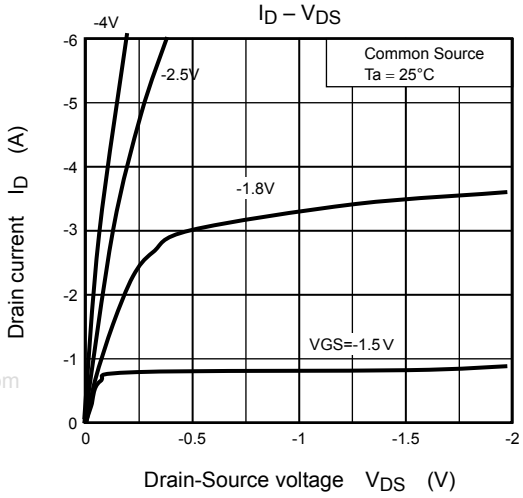
(b) V_{IN}

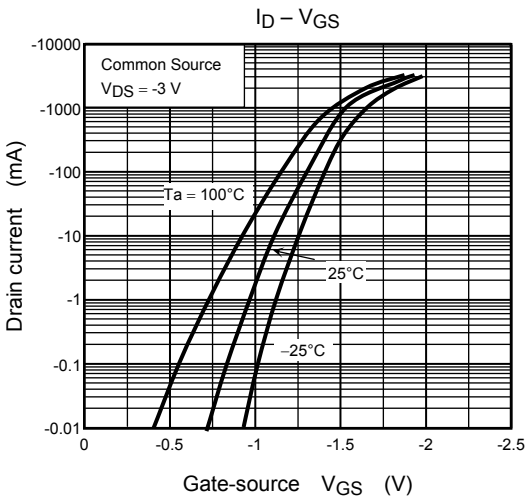
(c) V_{OUT}

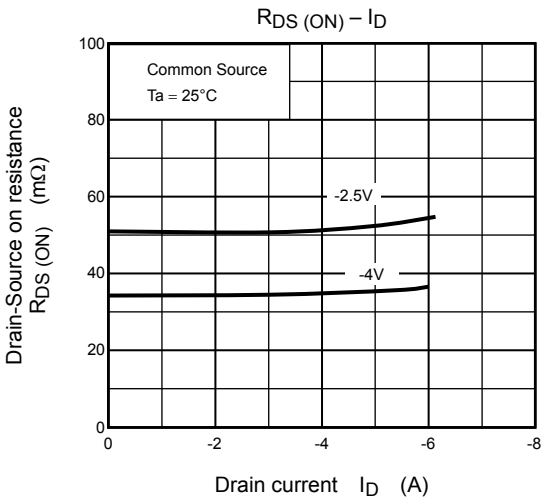


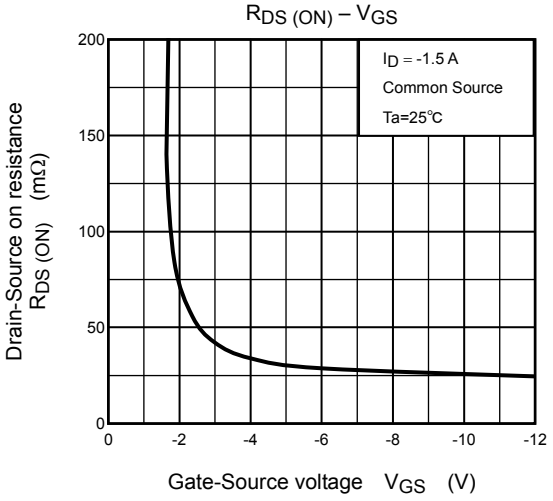
Precaution

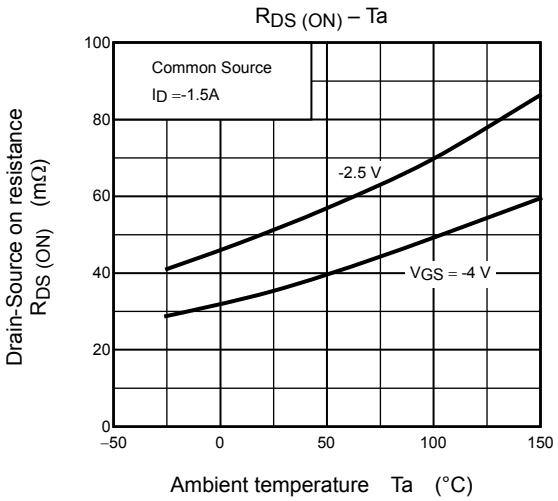
V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = -100 μA for this product. For normal switching operation, $V_{GS\ (on)}$ requires higher voltage than V_{th} and $V_{GS\ (off)}$ requires lower voltage than V_{th}.
(Relationship can be established as follows: $V_{GS\ (off)} < V_{th} < V_{GS\ (on)}$)
Please take this into consideration for using the device.

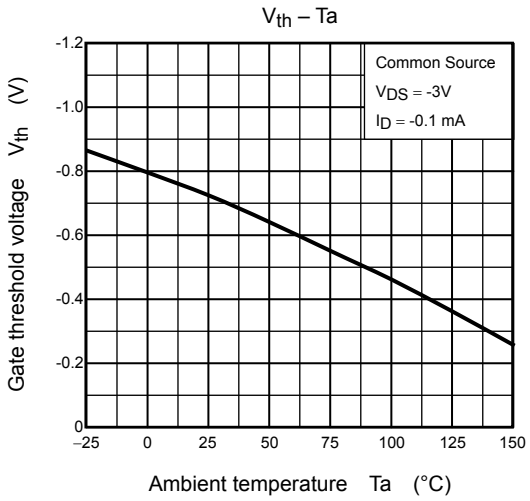




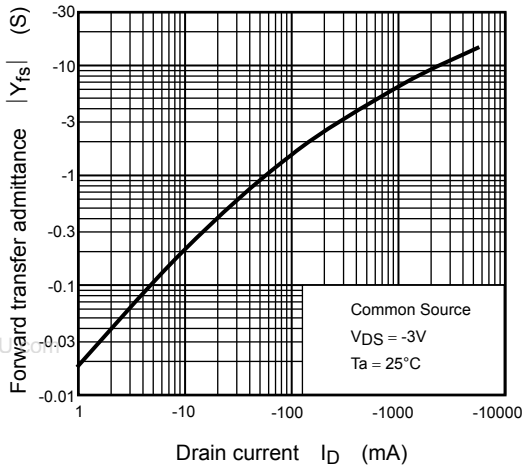




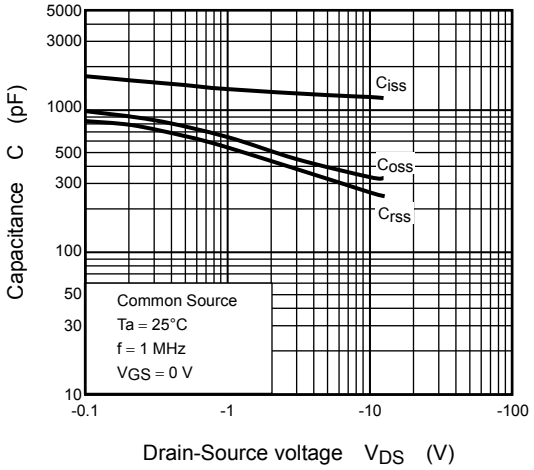




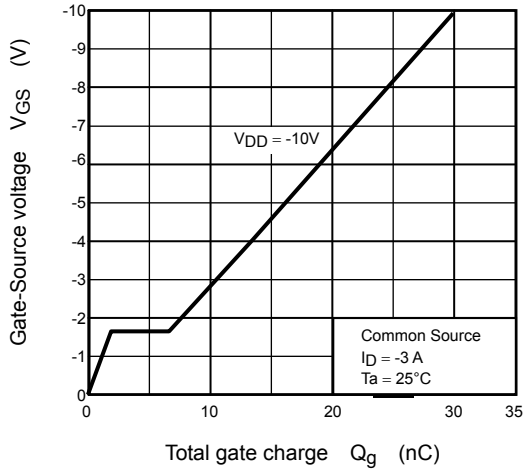
$|Y_{fs}| - I_D$



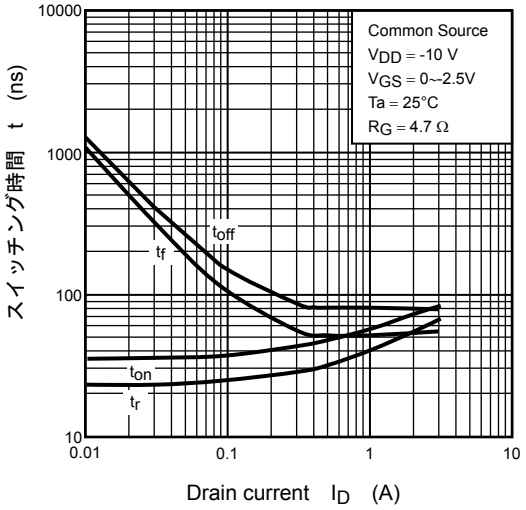
$C - V_{DS}$



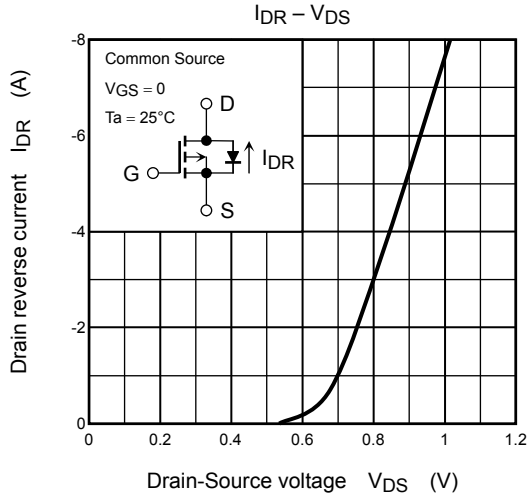
Dynamic Input Characteristic



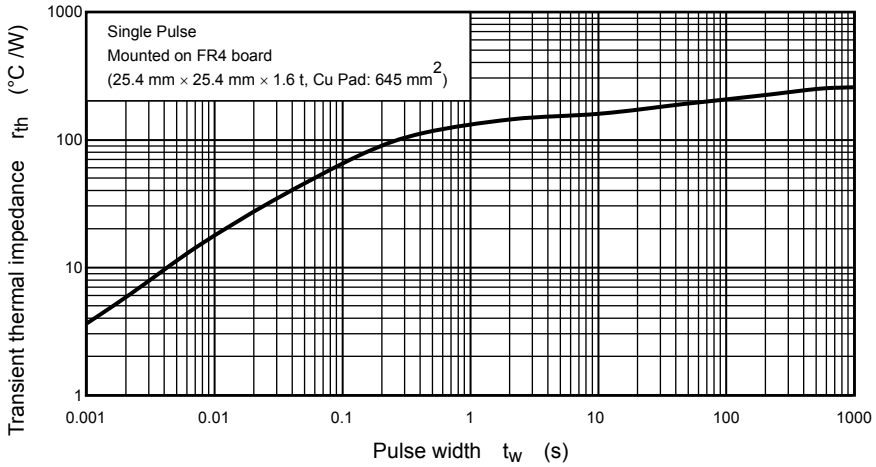
$t - I_D$



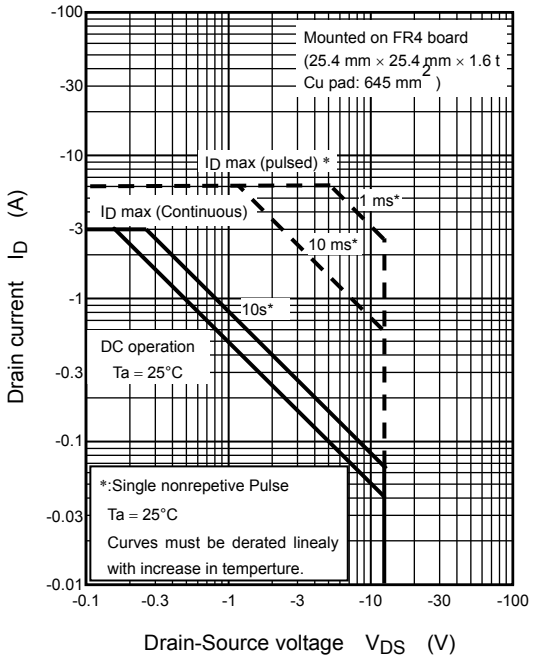
$I_{DR} - V_{DS}$



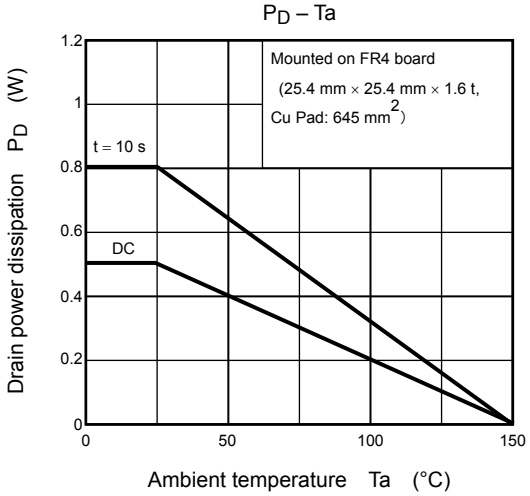
$r_{th} - t_w$



Safe operating area



P_D – Ta



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20070701-EN GENERAL

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